Data Sheet

August 2003

12MHz, High Input Impedance Operational Amplifier

intercil

HA-2600 is an internally compensated bipolar operational amplifier that features very high input impedance (500M Ω) coupled with wideband AC performance. The high resistance of the input stage is complemented by low offset voltage (0.5mV) and low bias and offset current (1nA) to facilitate accurate signal processing. Input offset can be reduced further by means of an external nulling potentiometer. 12MHz unity gain-bandwidth, 7V/µs slew rate and 150kV/V open-loop gain enables the HA-2600 to perform high-gain amplification of fast, wideband signals. These dynamic characteristics, coupled with fast settling times, make this amplifier ideally suited to pulse amplification designs as well as high frequency (e.g. video) applications. The frequency response of the amplifier can be tailored to exact design requirements by means of an external bandwidth control capacitor.

In addition to its application in pulse and video amplifier designs, the HA-2600 is particularly suited to other high performance designs such as high-gain low distortion audio amplifiers, high-Q and wideband active filters and highspeed comparators.

Ordering Information

| PART NUMBER | TEMP. RANGE (^o C) | PACKAGE | PKG. DWG. # | |
|-------------|----------------------------------|-----------------|----------------|--|
| HA2-2600-2 | -55 to 125 | 8 Pin Metal Can | T8.C | |

Features

| • Bandwidth 12MHz |
|--------------------------------|
| • High Input Impedance |
| Low Input Bias Current |
| Low Input Offset Current 1nA |
| Low Input Offset Voltage 0.5mV |
| • High Gain |
| • Slew Rate |
| |

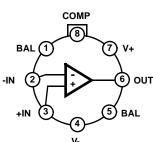
- Output Short Circuit Protection
- Unity Gain Stable

Applications

- Video Amplifier
- Pulse Amplifier
- · Audio Amplifiers and Filters
- High-Q Active Filters
- High-Speed Comparators
- Low Distortion Oscillators

Pinout





Absolute Maximum Ratings

 Supply Voltage Between V+ and V- Terminals
 45V

 Differential Input Voltage
 12V

 Peak Output Current
 Full Short Circuit Protection

Operating Conditions

Temperature Range

Thermal Information

| Thermal Resistance (Typical, Note 1) | θ _{JA} (^o C/W) | θ _{JC} (^o C/W) |
|--|-------------------------------------|--|
| Metal Can Package | 165 | 80 |
| Maximum Junction Temperature (Hermetic | Package) | 175 ⁰ C |
| Maximum Storage Temperature Range . | 65 | 5 ^o C to 150 ^o C |
| Maximum Lead Temperature (Soldering 1 | 0s) | 300 ⁰ C |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. θ_{JA} is measured with the component mounted on a low effective thermal conductivity test board in free air. See Tech Brief TB379 for details.

Electrical Specifications $V_{SUPPLY} = \pm 15V$, Unless Otherwise Specified

| PARAMETER | TEMP. (^o C) | MIN | TYP | MAX | UNITS |
|---|-------------------------|-----|------|-----|--------------------|
| INPUT CHARACTERISTICS | | | | | |
| Offset Voltage | 25 | - | 0.5 | 4 | mV |
| | Full | - | 2 | 6 | mV |
| Average Offset Voltage Drift | Full | - | 5 | - | μV/ ^o C |
| Bias Current | 25 | - | 1 | 10 | nA |
| | Full | - | 10 | 30 | nA |
| Offset Current | 25 | - | 1 | 10 | nA |
| | Full | - | 5 | 30 | nA |
| Differential Input Resistance (Note 11) | 25 | 100 | 500 | - | MΩ |
| Input Noise Voltage Density (f = 1kHz) | 25 | - | 11 | - | nV/√Hz |
| Input Noise Current Density (f = 1kHz) | 25 | - | 0.16 | - | pA/√Hz |
| Common Mode Range | Full | ±11 | ±12 | - | V |
| TRANSFER CHARACTERISTICS | | | | 1 | -1 |
| Large Signal Voltage Gain (Notes 2, 5) | 25 | 100 | 150 | - | kV/V |
| | Full | 70 | - | - | kV/V |
| Common Mode Rejection Ratio (Note 3) | Full | 80 | 100 | - | dB |
| Minimum Stable Gain | 25 | 1 | - | - | V/V |
| Gain Bandwidth Product (Note 4) | 25 | - | 12 | - | MHz |
| OUTPUT CHARACTERISTICS | | | | 1 | -1 |
| Output Voltage Swing (Note 2) | Full | ±10 | ±12 | - | V |
| Output Current (Note 5) | 25 | ±15 | ±22 | - | mA |
| Full Power Bandwidth (Notes 5, 12) | 25 | 50 | 75 | - | kHz |
| TRANSIENT RESPONSE (Note 11) | | | | | 1 |
| Rise Time (Notes 2, 6, 7, 8) | 25 | - | 30 | 60 | ns |
| Overshoot (Notes 2, 6, 7, 9) | 25 | - | 25 | 40 | % |
| Slew Rate (Notes 2, 6, 8, 13) | 25 | ±4 | ±7 | - | V/µs |
| Settling Time (Notes 2, 6, 14) | 25 | - | 1.5 | - | μs |

HA-2600

Electrical Specifications $V_{SUPPLY} = \pm 15V$, Unless Otherwise Specified (Continued)

| PARAMETER | TEMP. (^o C) | MIN | ТҮР | МАХ | UNITS |
|--|-------------------------|-----|-----|-----|-------|
| POWER SUPPLY CHARACTERISTICS | | | | | |
| Supply Current | 25 | - | 3 | 3.7 | mA |
| Power Supply Rejection Ratio (Note 10) | Full | 80 | 90 | - | dB |

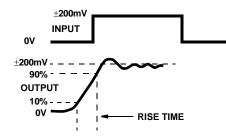
NOTES:

- 2. $R_L = 2k\Omega$.
- 3. $V_{CM} = \pm 10V$.
- 4. V_{OUT} < 90mV.
- 5. $V_{OUT} = \pm 10V$.
- 6. C_L = 100pF.
- 7. $V_{OUT} = \pm 200 \text{mV}.$
- 8. $A_V = +1$.
- 9. See Transient Response Test Circuits and Waveforms.
- 10. $\Delta V_{S} = \pm 5V.$
- 11. This parameter value guaranteed by design calculations.

 $\frac{\text{Slew Rate}}{2\pi V}_{\text{PEAK}}$ 12. Full Power Bandwidth guaranteed by slew rate measurement: FPBW =

- 13. $V_{OUT} = \pm 5V$
- 14. Settling time is characterized at $A_V = -1$ to 0.1% of a 10V step.

Test Circuits and Waveforms



NOTE: Measured on both positive and negative transitions from 0V to +200mV and 0V to -200mV at the output.

FIGURE 1. TRANSIENT RESPONSE

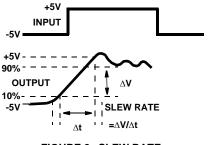
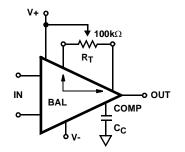
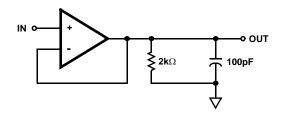


FIGURE 2. SLEW RATE



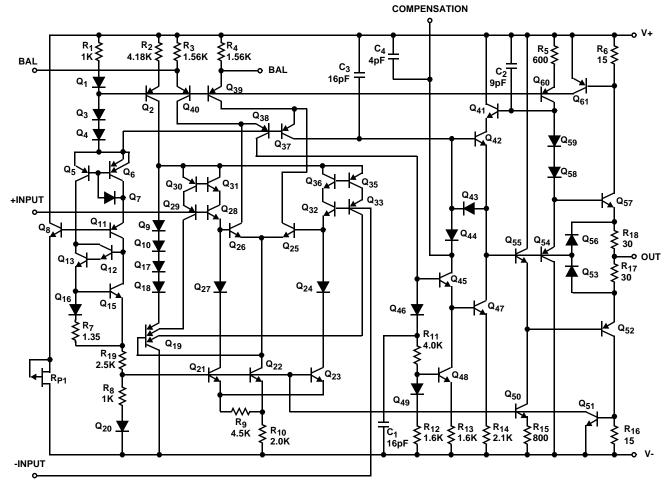
NOTE: Tested offset adjustment range is |VOS + 1mV| minimum referred to output. Typical ranges are $\pm 10 \text{mV}$ with $R_T = 100 \text{k}\Omega$.

FIGURE 4. SUGGESTED V_{OS} ADJUSTMENT AND **COMPENSATION HOOK UP**

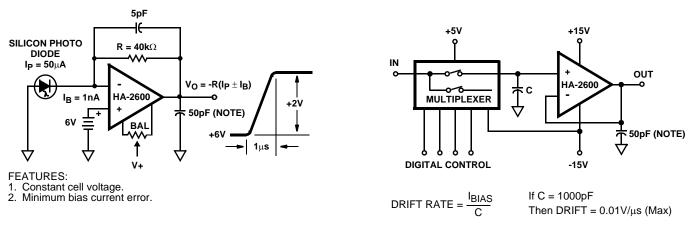




Schematic Diagram



Typical Applications



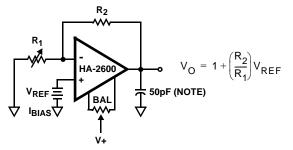
NOTE: A small load capacitance is recommended in all applications where practical to prevent possible high frequency oscillations resulting from external wiring parasitics. Capacitance up to 100pF has negligible effect on the bandwidth or slew rate.

FIGURE 5. PHOTO CURRENT TO VOLTAGE CONVERTER

4

FIGURE 6. SAMPLE AND HOLD

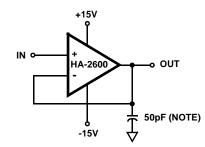
Typical Applications (Continued)



FEATURES:

1. Minimum bias current in reference cell.

2. Short Circuit Protection.

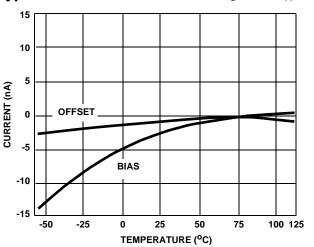


FEATURES

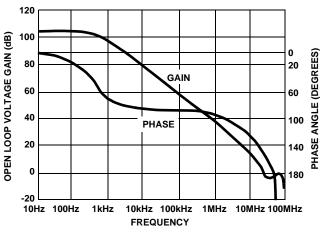
FIGURE 8. VOLTAGE FOLLOWER

NOTE: A small load capacitance is recommended in all applications where practical to prevent possible high frequency oscillations resulting from external wiring parasitics. Capacitance up to 100pF has negligible effect on the bandwidth or slew rate.

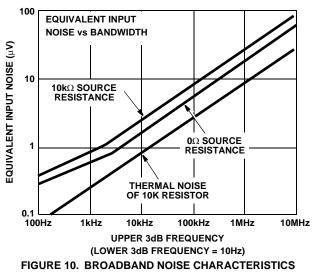
FIGURE 7. REFERENCE VOLTAGE AMPLIFIER











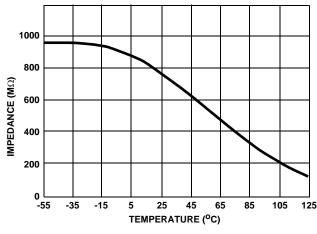
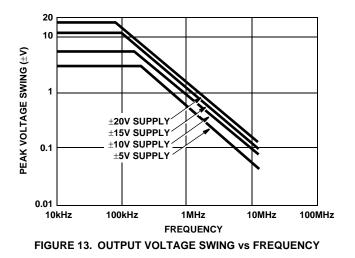


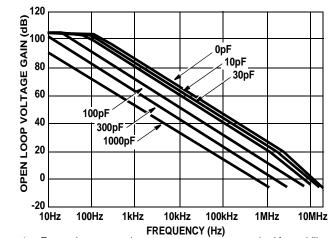
FIGURE 12. INPUT IMPEDANCE vs TEMPERATURE (100Hz)

Typical Performance Curves $V_S = \pm 15V$, $T_A = 25^{\circ}C$, Unless Otherwise Specified

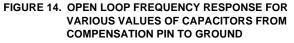
HA-2600

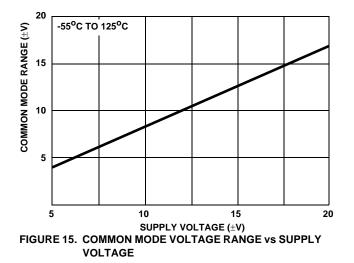
Typical Performance Curves $V_S = \pm 15V$, $T_A = 25^{\circ}C$, Unless Otherwise Specified (Continued)

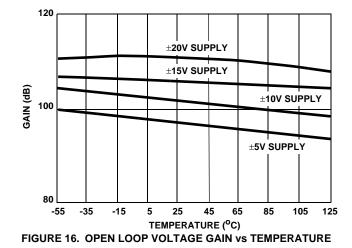




 External compensation components are not required for stability, but may be added to reduce bandwidth if desired. If External Compensation is used, also connect 100pF capacitor from output to ground.

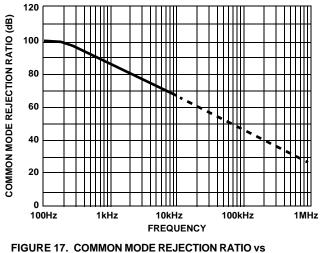




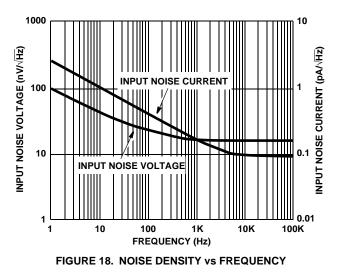


HA-2600

Typical Performance Curves $V_S = \pm 15V$, $T_A = 25^{\circ}C$, Unless Otherwise Specified (Continued)







Die Characteristics

DIE DIMENSIONS:

69 mils x 56 mils x 19 mils 1750µm x 1420µm x 483µm

METALLIZATION:

Type: Al, 1% Cu Thickness: 16kÅ ±2kÅ

SUBSTRATE POTENTIAL (Powered Up):

Unbiased

Metallization Mask Layout

PASSIVATION:

Type: Nitride (Si₃N₄) over Silox (SiO₂, 5% Phos.) Silox Thickness: $12k\mathring{A} \pm 2k\mathring{A}$ Nitride Thickness: $3.5k\mathring{A} \pm 1.5k\mathring{A}$

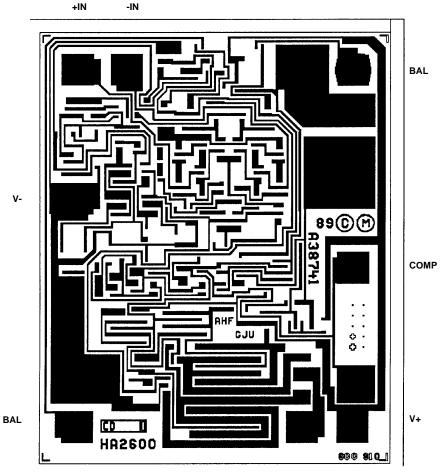
TRANSISTOR COUNT:

140

PROCESS:

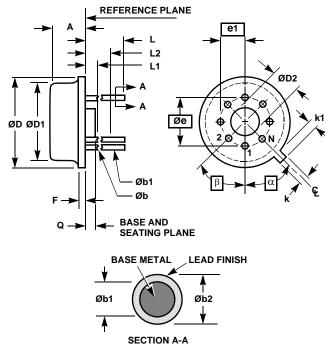
Bipolar Dielectric Isolation

HA-2600



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Metal Can Packages (Can)



NOTES:

- 1. (All leads) Øb applies between L1 and L2. Øb1 applies between L2 and 0.500 from the reference plane. Diameter is uncontrolled in L1 and beyond 0.500 from the reference plane.
- 2. Measured from maximum diameter of the product.
- 3. α is the basic spacing from the centerline of the tab to terminal 1 and β is the basic spacing of each lead or lead position (N -1 places) from α , looking at the bottom of the package.
- 4. N is the maximum number of terminal positions.
- 5. Dimensioning and tolerancing per ANSI Y14.5M 1982.
- 6. Controlling dimension: INCH.

T8.C MIL-STD-1835 MACY1-X8 (A1) 8 LEAD METAL CAN PACKAGE

| | INC | INCHES | | MILLIMETERS | | |
|--------|-----------------|-----------|---------------------|-------------|-------|--|
| SYMBOL | MIN | MAX | MIN | MAX | NOTES | |
| А | 0.165 | 0.185 | 4.19 | 4.70 | - | |
| Øb | 0.016 | 0.019 | 0.41 | 0.48 | 1 | |
| Øb1 | 0.016 | 0.021 | 0.41 | 0.53 | 1 | |
| Øb2 | 0.016 | 0.024 | 0.41 | 0.61 | - | |
| ØD | 0.335 | 0.375 | 8.51 | 9.40 | - | |
| ØD1 | 0.305 | 0.335 | 7.75 | 8.51 | - | |
| ØD2 | 0.110 | 0.160 | 2.79 | 4.06 | - | |
| е | 0.200 | 0.200 BSC | | 5.08 BSC | | |
| e1 | 0.100 | BSC | 2.54 | 4 BSC | - | |
| F | - | 0.040 | - | 1.02 | - | |
| k | 0.027 | 0.034 | 0.69 | 0.86 | - | |
| k1 | 0.027 | 0.045 | 0.69 | 1.14 | 2 | |
| L | 0.500 | 0.750 | 12.70 | 19.05 | 1 | |
| L1 | - | 0.050 | - | 1.27 | 1 | |
| L2 | 0.250 | - | 6.35 | - | 1 | |
| Q | 0.010 | 0.045 | 0.25 | 1.14 | - | |
| α | 45 ⁰ | BSC | 45 ⁰ BSC | | 3 | |
| β | 45 ⁰ | BSC | 45 ⁰ BSC | | 3 | |
| Ν | 8 | 3 | 8 | | 4 | |

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